

Generic Copy

Issue Date: 17-Sept-2010

TITLE: Copper Wire in the SOT563 and SOT723 Packages for MOSFET Products

PROPOSED FIRST SHIP DATE: 17-Dec-2010

AFFECTED CHANGE CATEGORY(S): ON Semiconductor Manufacturing Assembly

FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor Sales Office or Jennie Shen < Jennie.Shen@onsemi.com >

SAMPLES: Contact your local ON Semiconductor Sales Office or Brian Goodburn brian.goodburn@onsemi.com>

ADDITIONAL RELIABILITY DATA: Available

Contact your local ON Semiconductor Sales Office or Donna Scheuch <d.scheuch@onsemi.com>

NOTIFICATION TYPE:

Final Product/Process Change Notification (FPCN)

Final change notification sent to customers. FPCNs are issued at least 90 days prior to implementation of the change.

ON Semiconductor will consider this change approved unless specific conditions of acceptance are provided in writing within 30 days of receipt of this notice. To do so, contact <quality@onsemi.com>.

DESCRIPTION AND PURPOSE:

Referencing the ON Semiconductor General Announcement #GA16200: Conversion of Gold wire to Copper wire in ON Semiconductor's Assembly Facilities

ON Semiconductor is notifying customers of its use of Copper Wire in place of Gold Wire for their SOT563 and SOT723 Packaged Products. The SOT563 and SOT723 Products built with MOSFET Die are represented by this Process Change Notice.

Reliability Qualification and full electrical characterization over temperature have been performed.

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RELIABILITY DATA SUMMARY:

Reliability Test Results: NTK3142PT1H Test: Temperature Cycling (TC-PC)

Conditions: Ta=-65'C/150'C, Air-to-Air, Dwell >=10-min, 1000-cy, 3-Lots

Results: 0/240

Test: Bond Pull Strength Conditions: 3-Lots Results: 0/90

Test: Bond Pull Shear Conditions: 3-Lots Results: 0/90

Reliability Test Results: NTS2101PT1G
Test: High Temperature Reverse Bias (HTRB)

Conditions: Ta=150'C, Vds= 80% BVdss Rating, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: High Temperature Gate Bias (HTGB)

Conditions: Ta=150'C, Vds= 100% Vgs Rating, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: High Temperature Storage Life (HTSL) Conditions: Ta=175'C, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: High Temperature Storage Life (HTSL) Conditions: Ta=150'C, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: Intermittent Operating Life (IOL-PC)

Conditions: Ta=25'C, delta Tj=100'C, 2-min on/off, 15K- cy, 3-Lots

Results: 0/240

Test: Temperature Cycling (TC-PC)

Conditions: Ta=-65'C/150'C, Air-to-Air, Dwell >=10-min, 1000-cy, 3-Lots

Results: 0/240

Test: Autoclave Test (AC-PC)

Conditions: Ta=121'C, P=15psi, RH=100%, Duration: 96-Hrs, 3-Lots

Results: 0/240

Test: Highly Accelerated Stress Test (HAST)

Conditions: Ta=130'C, RH=85%, Duration: 96-Hrs, 3-Lots

Results: 0/240

Test: Bond Pull Strength Conditions: 4-Lots Results: 0/120

Test: Bond Pull Shear Conditions: 4-Lots Results: 0/120

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Reliability Test Results: NTZS3151PT1G
Test: High Temperature Reverse Bias (H3TRB)

Conditions: Ta=85'C, Relative Humidity= 85%, Vds= 80% BVdss Rating, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: Intermittent Operating Life (IOL-PC)

Conditions: Ta=25'C, delta Tj=100'C, 2-min on/off, 15K- cy, 3-Lots

Results: 0/240

Test: Temperature Cycling (TC-PC)

Conditions: Ta=-65'C/150'C, Air-to-Air, Dwell >=10-min, 1000-cy, 3-Lots

Results: 0/240

Test: Autoclave Test (AC-PC)

Conditions: Ta=121'C, P=15psi, RH=100%, Duration: 96-Hrs, 3-Lots

Results: 0/240

Test: Resistance to Solder Heat (RSH)

Tdwell= 10-Sec @ 260'C

Results: 0/90

Reliability Test Results: NTZS3151PT1G
Test: High Temperature Reverse Bias (H3TRB)

Conditions: Ta=85'C, Relative Humidity= 85%, Vds= 80% BVdss Rating, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: Intermittent Operating Life (IOL-PC)

Conditions: Ta=25'C, delta Tj=100'C, 2-min on/off, 15K- cy, 3-Lots

Results: 0/240

Test: Temperature Cycling (TC-PC)

Conditions: Ta=-65'C/150'C, Air-to-Air, Dwell >=10-min, 1000-cy, 3-Lots

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Conditions: Ta=121'C, P=15psi, RH=100%, Duration: 96-Hrs, 3-Lots

Results: 0/240

Test: Resistance to Solder Heat (RSH)

Tdwell= 10-Sec @ 260'C

Results: 0/90

Reliability Test Results: NTZD5110NT1G
Test: High Temperature Reverse Bias (HTRB)

Conditions: Ta=150'C, Vds= 80% BVdss Rating, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: High Temperature Gate Bias (HTGB)

Conditions: Ta=150'C, Vds= 100% Vgs Rating, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: High Temperature Storage Life (HTSL) Conditions: Ta=175'C, Duration: 1008-Hrs, 3-Lots

Results: 0/240

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Test: High Temperature Storage Life (HTSL) Conditions: Ta=150'C, Duration: 1008-Hrs, 3-Lots

Results: 0/240

Test: Highly Accelerated Stress Test (HAST)

Conditions: Ta=130'C, RH=85%, Duration: 96-Hrs, , 3-Lots

Results: 0/240

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Conditions: Ta=121'C, P=15psi, RH=100%, Duration: 96-Hrs, 3-Lots

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Results: 0/90

Reliability Test Results: NTZD5110NT1G
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Conditions: Ta=150'C, Vds= 80% BVdss Rating, Duration: 1008-Hrs, 3-Lots

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Conditions: Ta=121'C, P=15psi, RH=100%, Duration: 96-Hrs, 3-Lots

Results: 0/240

Test: Resistance to Solder Heat (RSH)

Tdwell= 10-Sec @ 260'C

Results: 0/90

ELECTRICAL CHARACTERISTIC SUMMARY:

There is no change in electrical parametric performance. Characterization data is available upon request.

CHANGED PART IDENTIFICATION:

There will be no physical change with products assembled with Copper Wire in place of Gold Wire. Products (listed on this FPCN) assembled with Copper Wire from the ON Semiconductor facility in Seremban, Malaysia, and in Leshan, China, will have a Finish Good Date Code representing Work Week 49, 2010 or newer.

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List of affected General Parts:

NTK3043NAT5G

NTK3043NT1G

NTK3043NT1H

NTK3043NT5H

NTK3134NT1G

1411/313414110

NTK3134NT1H

NTK3134NT5H

NTK3139PT1G

NTK3139PT1H

NTK3139PT5G

NTK3139PT5H NTK3142PT1G

1111/31427 110

NTK3142PT1H

NTK3142PT5G

NTK3142PT5H

NTZS3151PT1G

NTZS3151PT1H

NTZD3152PT1G

NTZD3152PT1H

NTZD3154NT1G

NTZD3154NT1H

NTZD3154NT2H NTZD3154NT5G

NTZD3154NT5G

NTZD3155CT1G

NTZD3155CT1H

NTZD3155CT2G

NTZD3155CT2H

NTZD3155CT5G

NTZD3155CT5H

NTZD5110NT1G

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